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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/627,796	07/25/2003	Taner Dosluoglu	DSR14725	2665
75	590 08/24/2004		EXAMINER	
George O. SAILE			LOKE, STEVEN HO YIN	
28 DAVIS AVI POUGHKEEPS	SIE, NY 12603		ART UNIT	PAPER NUMBER
	•		2811	
			DATE MAILED: 08/24/2004	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(a)				
	Application No.	Applicant(s)	Applicant(s)			
Office Action Comments	10/627,796	DOSLUOGLU, TA	DOSLUOGLU, TANER			
Office Action Summary	Examiner	Art Unit				
	Steven Loke	2811	pr			
The MAILING DATE of this communication Period for Reply	on appears on the cover sheet w	ith the correspondence ad	ldress			
A SHORTENED STATUTORY PERIOD FOR F THE MAILING DATE OF THIS COMMUNICAT - Extensions of time may be available under the provisions of 37 of after SIX (6) MONTHS from the mailing date of this communicat - If the period for reply specified above is less than thirty (30) days - If NO period for reply is specified above, the maximum statutory - Failure to reply within the set or extended period for reply will, by Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ION. CFR 1.136(a). In no event, however, may a ion. s, a reply within the statutory minimum of thi period will apply and will expire SIX (6) MO a statute, cause the application to become A	reply be timely filed rty (30) days will be considered timel NTHS from the mailing date of this c BANDONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on						
2a) This action is FINAL . 2b) ⊠	This action is non-final.					
	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposition of Claims						
4)⊠ Claim(s) <u>1-26</u> is/are pending in the applic 4a) Of the above claim(s) is/are wi 5)□ Claim(s) is/are allowed. 6)⊠ Claim(s) <u>10</u> is/are rejected. 7)⊠ Claim(s) <u>1-9 and 11-26</u> is/are objected to 8)□ Claim(s) are subject to restriction	thdrawn from consideration.					
Application Papers						
9) The specification is objected to by the Example 10) The drawing(s) filed on is/are: a) Applicant may not request that any objection Replacement drawing sheet(s) including the control of the oath or declaration is objected to by the control of the oath or declaration is objected.	☐ accepted or b)☐ objected to to the drawing(s) be held in abeya correction is required if the drawing	ance. See 37 CFR 1.85(a). g(s) is objected to. See 37 C				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for for a) All b) Some * c) None of: 1. Certified copies of the priority documents of the priority documents. 2. Certified copies of the priority documents. 3. Copies of the certified copies of the application from the International Experiments. * See the attached detailed Office action for	uments have been received. uments have been received in a e priority documents have bee Bureau (PCT Rule 17.2(a)).	Application No n received in this National	Stage			
Attachment(s)						
1) Notice of References Cited (PTO-892)		Summary (PTO-413)				
 2) Notice of Draftsperson's Patent Drawing Review (PTO-9-3) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/Paper No(s)/Mail Date 10/29/03. 		v(s)/Mail Date Informal Patent Application (PT 	O-152)			

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1. The disclosure is objected to because of the following informalities: The written description (page 7, line 13) shows the PN junction 15 is formed between the P well 14 and the N well 12. However, Fig. 1 shows the PN junction [15] is formed between the n-well [12] and the p-type substrate [10]. Therefore, it is unclear where is the correct PN junction [15] in the specification.

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Appropriate correction is required.

- 2. The specification is objected to as failing to provide proper antecedent basis for the claimed subject matter. See 37 CFR 1.75(d)(1) and MPEP § 608.01(o). Correction of the following is required: The phrase "accumulating charge at the PN junction between said P well and said N well during a charge integration period" in claim 1. The claimed subject matters of claims 2 and 4. The phrase "accumulating charge at the PN junction between said N well and said P well during a charge integration period" in claim 8. The claimed subject matters of claims 9, 11, 17 and 23.
- 3. Claims 1-26 are objected to because of the following informalities: Claims 1, 8, 15, 21, line 8, the phrase "said the thickness" has no antecedent basis. Claim 13, lines 1-2, the phrase "said resetting the potential between said P well and said substrate" has no antecedent basis. Claim 14, the phrase "said determining the potential of said gate" has no antecedent basis. Claim 15, lines 14-15, the phrase "said means for determining the potential of said floating gate" has no antecedent basis. Claim 25, lines 1-2, the phrase "said means for resetting the potential between said P well and said substrate" has no antecedent basis. Claim 26, lines 1-2, the phrase "said means for

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reading the potential of said gate" has no antecedent basis. Appropriate correction is required.

4. Claim 10 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 10, lines 2-3, the phrase "forming an electrical connection between said contact region formed in said P well and a means for resetting the potential between said P well and said substrate" is vague and indefinite. The specification (page 10, lines 1-8) and claim 8 disclose there is no contact regions in the P well and a means for resetting the potential between said N well and said substrate. In addition, the contact region [20] is formed in the N well [14]. Therefore, the phrase should rewrite as "forming an electrical connection between said contact region formed in said N well and a means for resetting the potential between said N well and said substrate" in claim 10.

- 5. Claims 1-9 and 11-26 would be allowable if rewritten or amended to overcome the objections set forth in this Office action.
- 6. The following is a statement of reasons for the indication of allowable subject matter: The first major difference in the claims not found in the prior art of record is the steps comprising: resetting the potential between said P well and said substrate during a reset period wherein a tunneling current between said P well and said floating gate resets the potential of said floating gate; accumulating charge at the PN junction between said P well and said N well during a charge integration period, wherein said charge integration period follows said reset period; and reading the potential of said

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gate after said charge integration period has been completed. The second major difference in the claims not found in the prior art of record is the steps comprising: resetting the potential between said N well and said substrate during a reset period wherein a tunneling current between said N well and said floating gate resets the potential of said floating gate; accumulating charge at the PN junction between said N well and said P well during a charge integration period, wherein said charge integration period follows said reset period; and reading the potential of said gate after said charge integration period has been completed. The third major difference in the claims not found in the prior art of record is the means for reading or determining the potential of said gate, wherein the only electrical connection to said floating gate is to connect said floating gate to said means for reading or determining the potential of said floating gate.

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Steven Loke whose telephone number is (571) 272-1657. The examiner can normally be reached on 7:50 am to 5:20 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (571) 272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

sl August 22, 2004 Steven Loke Primary Examiner